Berry phase and quantized Halle ect in three-dim ension

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Berry recognized that in quantum mechanics a geometrical phase (Berry phase) arises from the adiabatic process of a system around a closed loop in the parameter space. It has been shown that the topological form ula for the Hall conductivity of two-dimensional Bloch electrons 3,4 can be written in terms of the Berry phase. We demonstrate that the above argument is generalized in the three dimensional systems. The Berry phase we consider here is induced by the adiabatic change of the time-dependent vector potential, which represents the electric eld as well as the magnetic eld. Throughout this note, we use the unit h = c = 1.

We consider Bloch electrons in a uniform magnetic eld in three dimensions. When we consider the \rational ux" introduced in Ref. 6, we can choose one of the primitive vectors of the Bravais lattice c parallel to the magnetic eld, and also we can not the other two a and b. Then, we take the magnetic eld

$$B = \frac{1}{v_0} \frac{2}{e} \frac{p}{Q} c;$$
 (1)

where $v_0 = a$ (b c), p and Q are integers and 0 < Q. The system has the magnetic translation symmetry, and in this case, we can choose the magnetic unit cellwith the primitive vectors a, Qb, and c. Let $G_a = (2 = v_0)$ (b c); $G_b = (2 = v_0)$ (c a) and $G_c = (2 = v_0)$ (a b) stand for the primitive vectors of the reciprocal lattice. Then, the magnetic B rillouin zone (MBZ) is written as,

$$k = f_1G_a + (f_2=Q)G_b + f_3G_c; 0 < f_1; f_2; f_3 < 1:(2)$$

For the magnetic translation symmetry, the wavefunction is written in the Bloch form

$$_{k}^{n}(\mathbf{r}) = e^{ik} \tilde{\mathbf{t}}_{k}^{n}(\mathbf{r}); \tag{3}$$

where u_k^n has a property

$$u_{\nu}^{n} (r + R^{0}) = e^{iR^{0}} u_{\nu}^{n} (r);$$
 (4)

where $R^0 = la + mQb + nc$ (l;m;n; integer) and A is the vector potential for the electrom agnetic eld.

It has been shown that, when the Ferm i energy is located in the energy gap, the Hall conductivity for the

three-dim ensional Bloch electrons is written as

$$_{ij} = \frac{e^2}{4^{2}} \mathbf{u}_{ijk} G_k;$$

$$G = (t_a G_a + t_b G_b + t_c G_c)$$
 (5)

where i; j; k = x; y; z The coe cients t_a , t_b and t_c are the topological numbers and take integer values. For example, t_c is written as

$$t_{c} = \frac{X}{c} \int_{0}^{Z} df_{3} \int_{0}^{(n^{0})} (f_{3}) df_{3} \int_{0}^{(n)} (f_{3}) df_{3} \int_{0}^{(n$$

where we introduce the vector eld de ned by,

$$a_n(k) = \langle u_k^n \dot{\tau}_k \dot{u}_k^n \rangle :$$
 (7)

The su ces n and n 0 are the band indices and the sum mation is taken over all the bands below the Ferm i energy. The integral $_0^1$ df $_3$ $_{S\,(f_3)}$ d^2k shows the k integral over the MBZ. The expression of $_c^{(n)}\,(f_3)$ is the Chem number of the ber bundle de ned on S (f_3) , i.e. twotorus, whose connection is $a_n\,(k)$. It becomes integer and does not depend on f_3 when the n-th band does not cross the Ferm i level. The detailed discussion can be seen in Ref. 4 and Ref. 6. It can be shown that the other integers t_a and t_b are also equivalent to the Chem number as the same manner.

Following Ref. 5, we derive the Berry phase of this system. We consider the time-dependent Schrodinger equation

$$i\frac{\theta(t)}{\theta+} = \frac{1}{2m} (ir + eA(t))^2 + U(r)(t);$$
 (8)

where U(r) = U(r + la + mb + nc) and A(t) is the timedependent vector potential for the electrom agnetic eld. Therefore, we consider not only the uniform magnetic eld Eq. (1), but also the electric eld. We use the adiabatic approximation. It means that we introduce a weak electric eld. According to Berry¹⁾ and by using the Bloch form Eq. (3), the wave function of the electron for the n-th band at time t can be written with a phase n(t) as

where the function u_k^n (t;r) and E_{nk} (t) are obtained by

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solving the instantaneous eigenvalue equation

$$H_k(t)u_k^n(t;r) = \frac{1}{2m} (\text{ ir } + k + eA(t))^2 + U(r) u_k^n(t;r)$$
 for useful discussions.

$$= E_{nk}(t)u_k^n(t;r):$$
 (10)

The time-dependent part of the vector potential is written as Et. Substitute Eq. (9) into Eq. (8) and use Eq. (10), then $_{n}$ (t) is obtained as

$$\begin{array}{lll}
 & & Z_{t} \\
 & & dt^{0} & u_{k}^{n} (t^{0}) \frac{\theta}{\theta t^{0}} u_{k}^{n} (t^{0}) \\
 & & Z_{t}^{0} \\
 & & dt^{0} & u_{k}^{n} e_{E t^{0}} \frac{\theta}{\theta t^{0}} u_{k}^{n} e_{E t^{0}} :
\end{array}$$
(11)

In order to consider the Berry phase, a Ham iltonian must go around a closed loop in a parameter space in adiabatic process. The Ham iltonian H_k (t) as it is not have this property. However, it is possible to compactify it into the magnetic Brillouin zone as $H_{f_1+1;f_2;f_3}$ (t) $H_{f_1;f_2+1;f_3}$ (t) $H_{f_1;f_2;f_3+1}$ (t) $H_{f_1;f_2;f_3}$ (t), where f_1 , f_2 and f_3 parameterize k as Eq. (2). Therefore, in the case that $E = G_a$, $E = G_b$ and $E = G_c$, Berry phases are obtained from Eq. (11) as

$$Z_{1}$$

$$(f_{2};f_{3}) = i df_{1}G_{a} (k);$$

$$Z_{1}$$

$$(f_{3};f_{1}) = i df_{2}G_{b} (k);$$

$$Z_{1}$$

$$(f_{1};f_{2}) = i df_{3}G_{c} (k);$$

$$(12)$$

respectively. By using the Stokes theorem in Eq. (6), $t_{\rm c}$ can be written in term s of Berry phase as

$$t_{c} = \frac{1}{2} \sum_{n^{0} = n = 0}^{X} df_{3}$$

$$Z_{1}$$

$$df_{1} \frac{d}{df_{1}} \int_{b}^{(n^{0})} (f_{3}; f_{1}) \int_{0}^{Z_{1}} df_{2} \frac{d}{df_{2}} \int_{a}^{(n^{0})} (f_{2}; f_{3});$$
(13)

where $_{b}^{(n^0)}$ (f₃;f₁) is the Berry phase for the band n^0 below the Ferm ienergy induced by the electric eld along G_b. The symbol $_{n^0-n}$ denotes that the sum mation is taken over all the bands below the Ferm ienergy. Similarly, we can show that t_a and t_b are also written in terms of the Berry phases as

$$t_{a} = \frac{1}{2} \sum_{i_{n^{0} n^{0} 0}}^{X} \sum_{i_{n^{0} n^{0} 0}}^{Z} df_{1}$$

$$\sum_{i_{n^{0} n^{0} 0}}^{Z} \frac{d}{df_{2}} \sum_{i_{n^{0} n^{0} 0}}^{(n^{0})} (f_{1}; f_{2}) \sum_{i_{n^{0} n^{0} 0}}^{Z} df_{3} \frac{d}{df_{3}} \sum_{i_{n^{0} n^{0} 0}}^{(n^{0})} (f_{3}; f_{1}) ;$$

$$t_{b} = \frac{1}{2} \sum_{i_{n^{0} n^{0} 0}}^{X} df_{2}$$

$$\sum_{i_{n^{0} n^{0} 0}}^{Z} df_{3} \frac{d}{df_{3}} \sum_{i_{n^{0} 0}}^{(n^{0})} (f_{2}; f_{3}) \sum_{i_{n^{0} 0}}^{Z} df_{1} \frac{d}{df_{1}} \sum_{i_{n^{0} 0}}^{(n^{0})} (f_{1}; f_{2}) ;$$

$$(14)$$

Therefore, three-dim ensional quantized Hall conductivity is closely related to the Berry phase. This result is the 3D generalization of that which was pointed out in

Ref. 5.

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